

# **Surface Mount RF PIN Attenuator Diodes**

# **Technical Data**

#### **HSMP-380x Series**

#### **Features**

- Diodes Optimized for Low Distortion Attenuating
- Surface Mount Packages
   Single and Dual Versions
   Tape and Reel Options
   Available
- Low Failure in Time (FIT)
  Rate<sup>[1]</sup>

#### Note:

 For more information see the Surface Mount PIN Reliability Data Sheet.

### Package Lead Code Identification, SOT-23 (Top View)







### **Description/Applications**

The HSMP-380x series is specifically designed for low distortion attenuator applications while drawing slightly less current than the ultra-low distortion HSMP-381x series.

A SPICE model is not available for PIN diodes as SPICE does not provide for a key PIN diode characteristic, carrier lifetime.

Note: The HSMP-381x series is recommended for new designs.

# Absolute Maximum Ratings $^{[1]}$ $T_A = 25^{\circ}C$

| Symbol           | Parameter                    | Units             | Absolute Maximum        |
|------------------|------------------------------|-------------------|-------------------------|
| $I_{\rm f}$      | Forward Current (1 ms Pulse) | Amp               | 1                       |
| P <sub>t</sub>   | Total Device Dissipation     | mW <sup>[2]</sup> | 250                     |
| P <sub>iv</sub>  | Peak Inverse Voltage         | _                 | Same as V <sub>BR</sub> |
| T <sub>j</sub>   | Junction Temperature         | °C                | 150                     |
| T <sub>STG</sub> | Storage Temperature          | °C                | -65 to 150              |

#### Notes:

- Operation in excess of any one of these conditions may result in permanent damage to this device.
- 2. CW Power Dissipation at  $T_{LEAD}$  = 25°C. Derate to zero at maximum rated temperature.

# Electrical Specifications $T_A = 25^{\circ}C$ (Each Diode)

| Part<br>Number<br>HSMP- | Package<br>Marking<br>Code <sup>[1]</sup> | Lead<br>Code | Configuration  | Nearest<br>Equivalent<br>Axial Lead<br>Part No.<br>5082- | Minimum<br>Breakdown<br>Voltage<br>V <sub>BR</sub> (V) | $\begin{array}{c} \textbf{Maximum} \\ \textbf{Series} \\ \textbf{Resistance} \\ \textbf{R}_{S}\left(\Omega\right) \end{array}$ | Maximum<br>Total<br>Capacitance<br>C <sub>T</sub> (pF) | $\begin{array}{c} \textbf{Minimum} \\ \textbf{High} \\ \textbf{Resistance} \\ \textbf{R}_{\textbf{H}} \left( \Omega \right) \end{array}$ | $\begin{array}{c} \textbf{Maximum} \\ \textbf{Low} \\ \textbf{Resistance} \\ \textbf{R}_{L}\left(\Omega\right) \end{array}$ |
|-------------------------|---|--------------|----------------|--|--|--|--|--|---|
| 3800                    | D0  | 0            | Single         | 3080   | 100  | 2.0  | 0.37   | 1000   | 8   |
| 3802                    | D2  | 2            | Series         |  |  |  |  |  |   |
| 3804                    | D4  | 4            | Common Cathode |  |  |  |  |  |   |
| Test Conditions         |   |              | $V_R = V_{BR}$ | $I_F = 100 \text{ mA}$                                   | $V_R = 50 \text{ V}$                                   | $I_F = 0.01 \text{ mA}$  | $I_F = 20 \text{ mA}$                                  |  |   |
|                         |   |              |                |  | Measure  | f = 100  MHz   | f = 1  MHz   | f = 100 MHz  | f= 100 MHz  |
|                         |   |              |                |  | $I_R \le 10 \mu A$                                     |  |  |  |   |

#### **Note:**

1. Package marking code is white.

## Typical Parameters at $T_A = 25^{\circ}C$

| Part Number<br>HSMP- | Series Resistance $R_S$ ( $\Omega$ )       | Carrier Lifetime τ (ns)                      | Reverse Recovery Time<br>T <sub>rr</sub> (ns)   | Total Capacitance<br>C <sub>T</sub> (pF) |
|----------------------|--|--|---|--|
| 380x                 | 55   | 1800   | 500   | 0.32 @ 50 V                              |
| Test Conditions      | $I_F = 1 \text{ mA}$ $f = 100 \text{ MHz}$ | $I_F = 50 \text{ mA}$ $I_R = 250 \text{ mA}$ | $\begin{array}{c} V_R = 10 \text{ V} \\ I_F = 20 \text{ mA} \\ 90\% \text{ Recovery} \end{array}$ |  |

# Typical Parameters at $T_A$ = 25°C (unless otherwise noted), Single Diode

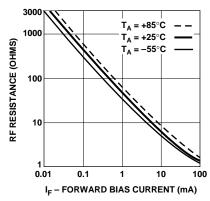


Figure 1. RF Resistance vs. Forward Bias Current.

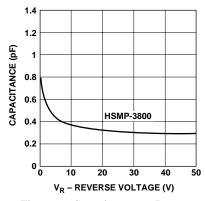


Figure 2. Capacitance vs. Reverse Voltage.

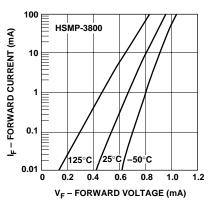
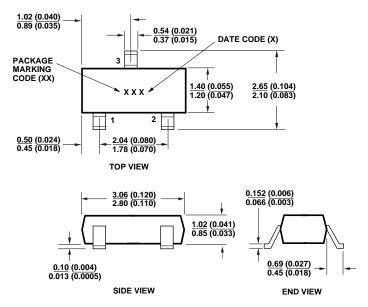


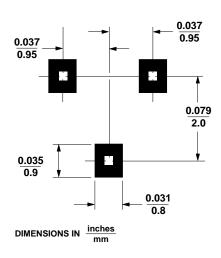
Figure 3. Forward Current vs. Forward Voltage.

## Package Dimensions Outline 23 (SOT-23)



**DIMENSIONS ARE IN MILLIMETERS (INCHES)** 

# **PC Board Footprints** SOT-23



### **Package Characteristics**

| 0                             |                     |
|-------------------------------|---------------------|
| Lead Material                 | Alloy 42            |
| Lead Finish                   | Tin-Lead 85-15%     |
| Maximum Soldering Temperature | 260°C for 5 seconds |
| Minimum Lead Strength         | 2 pounds pull       |
| Typical Package Inductance    | 2 nH                |
| Typical Package Capacitance   |                     |



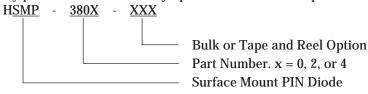
### **Profile Option Descriptions**

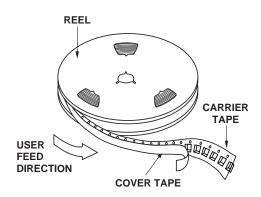
- -BLK = Bulk
- -TR1 = 3K pc. Tape and Reel, Device Orientation; See Figures 4 and 5
- -TR2 = 10K pc. Tape and Reel, Device Orientation; See Figures 4 and 5

Tape and Reeling conforms to Electronic Industries RS-481, "Taping of Surface Mounted Components for Automated Placement."

### **Ordering Information**

Specify part number followed by option under. For example:





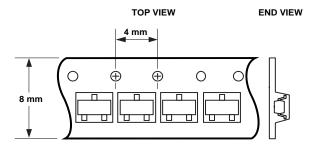


Figure 4. Options -TR1, -TR2 for SOT-23 Packages.

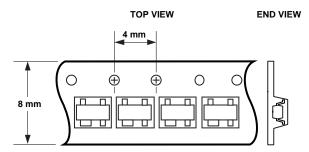


Figure 5. Options -TR1, -TR2 for SOT-143 Packages.

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Data subject to change.
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Obsoletes 5968-2350E, 5968-3435E
5968-8015E (11/99)